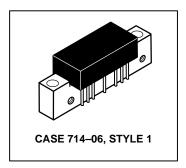
The RF Line 450 MHz CATV Amplifier

... designed for broadband applications requiring low distortion characteristics. Specified for use as a CATV trunk–line amplifier. Features ion–implanted arsenic emitter transistors with 7.0 GHz f_T, and an all gold metallization system.

- Specified for 53- and 60-Channel Performance
- Broadband Power Gain @ f = 40-450 MHz $G_D = 12.5 \text{ dB (Typ)}$
- Broadband Power Gain @ f = 40-450 MHz
 G_D = 12.5 dB (Typ)
- Broadband Noise Figure @ f = 450 MHz
 NF = 7.0 dB (Typ)
- Superior Gain, Return Loss and DC Current Stability with Temperature

MHW5122A

12.5 dB GAIN 450 MHz 60-CHANNEL CATV TRUNK AMPLIFIER



ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V _{in}	+70	dBmV
DC Supply Voltage	Vcc	+28	Vdc
Operating Case Temperature Range	T _C	-20 to +100	°C
Storage Temperature Range	T _{stg}	-40 to +100	°C

ELECTRICAL CHARACTERISTICS (V_{CC} = 24 Vdc, T_C = +30°C, 75 Ω system unless otherwise noted)

Characteristic	_	Symbol	Min	Тур	Max	Unit
Frequency Range		BW	40	_	450	MHz
Power Gain — 50 MHz		Gp	12	12.5	13	dB
Slope		S	+0.2	+0.7	+1.5	dB
Gain Flatness (Peak To Valley)		_	_	0.2	0.4	dB
Return Loss — Input/Output (Z ₀ = 75 Ohms)	40-450 MHz	IRL/ORL	18	_	_	dB
Second Order Intermodulation Distortion (V _{out} = +46 dBmV per ch., Ch 2, M6, M (V _{out} = +46 dBmV per ch., Ch 2, M13,		IMD		-78 -	_ -72	dB
Cross Modulation Distortion (V _{out} = +46 dBmV per ch.)	53-Channel FLAT 60-Channel FLAT	XMD ₅₃ XMD ₆₀	_ _	-63 -63	— –61	dB
Composite Triple Beat (Vout = +46 dBmV per ch.)	53-Channel FLAT 60-Channel FLAT	СТВ ₅₃ СТВ ₆₀	_ _	-63 -61	_ -58	dB
DIN (European Applications Only)* 300 MHz — (CH V + Q - P @ W) 400 MHz — (CH M8 + M15 - M9 @ M1 450 MHz — (CH M20 + M23 - M22 @	,	DIN1 DIN2 DIN3	_ _ _	125 124 123	_ _ _ _	dBμV**
Noise Figure (f = 450 MHz)		NF	_	7.0	8.0	dB
DC Current		I _{DC}	_	200	240	mA

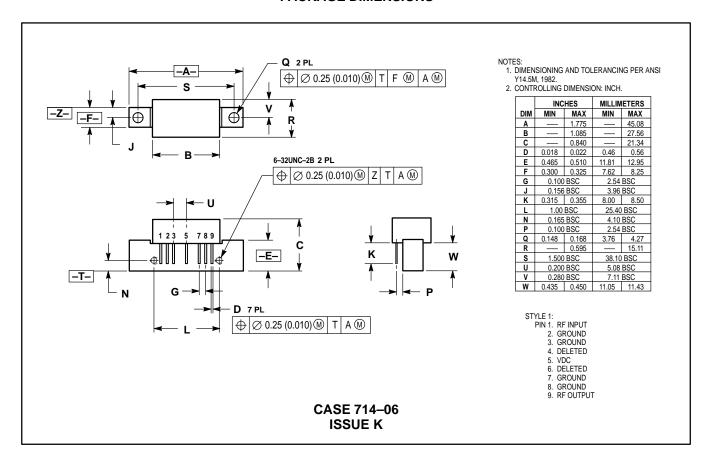


*DIN (European Applications Only)

NCTA Channel	Frequency	DIN Output Level	DIN Beat Level
Designation	(MHz)	(dBmV)** (Typ)	dB Relative to Ref. Ch.
P	253.25	+59	≤-60
Q	259.25	+59	
V	289.25	+65	
W (Ref.)	295.25	+65	
M8	361.25	+58	≤-60
M9	367.25	+58	
M14 (Ref.)	397.25	+64	
M15	403.25	+64	
M20	433.25	+63	≤-60
M21 (Ref.)	439.25	+63	
M22	445.25	+57	
M23	451.25	+57	

^{**} DIN (dB μ V) = Reference Channel Level (dBmV) +60 dB

PACKAGE DIMENSIONS



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